

# SHINDENGEN

## HVX-2 Series Power MOSFET

N-Channel Enhancement type

**2SK2664  
( F3V90HVX2 )**

**900V 3A**

### FEATURES

Input capacitance ( $C_{iss}$ ) is small.  
Especially, input capacitance at 0 bias is small.

The static  $R_{ds(on)}$  is small.

The switching time is fast.

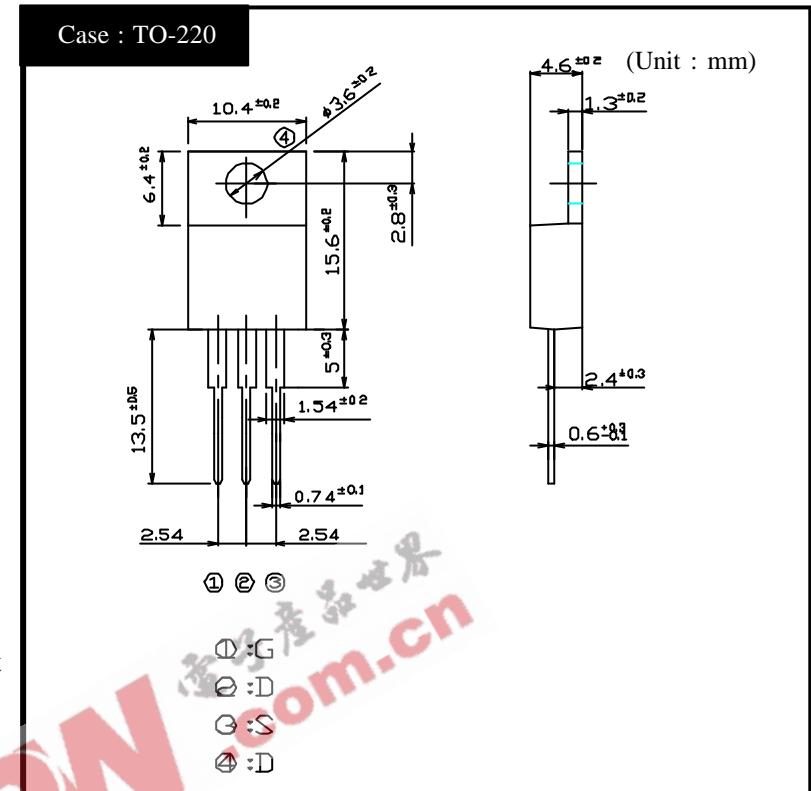
Avalanche resistance guaranteed.

### APPLICATION

Switching power supply of AC 240V input  
High voltage power supply

Inverter

### OUTLINE DIMENSIONS



### RATINGS

Absolute Maximum Ratings ( $T_c = 25^\circ C$ )

Item	Symbol	Conditions	Ratings	Units
Storage Temperature	$T_{stg}$		-55 ~ 150	
Channel Temperature	$T_{ch}$		150	
Drain-Source Voltage	$V_{DSS}$		900	V
Gate-Source Voltage	$V_{GSS}$		$\pm 30$	
Continuous Drain Current (DC)	$I_D$		3	
Continuous Drain Current (Peak)	$I_{DP}$	Pulse width 10 $\mu s$ , Duty cycle 1/100	6	A
Continuous Source Current (DC)	$I_S$		3	
Total Power Dissipation	$P_T$		50	W
Repetitive Avalanche Current	$I_{AR}$	$T_{ch} = 150$	3	A
Single Avalanche Energy	$E_{AS}$	$T_{ch} = 25$	48	mJ
Repetitive Avalanche Energy	$E_{AR}$	$T_{ch} = 25$	4.8	
Mounting Torque	$T_{OR}$	(Recommended torque : 0.3 N·m)	0.5	N·m

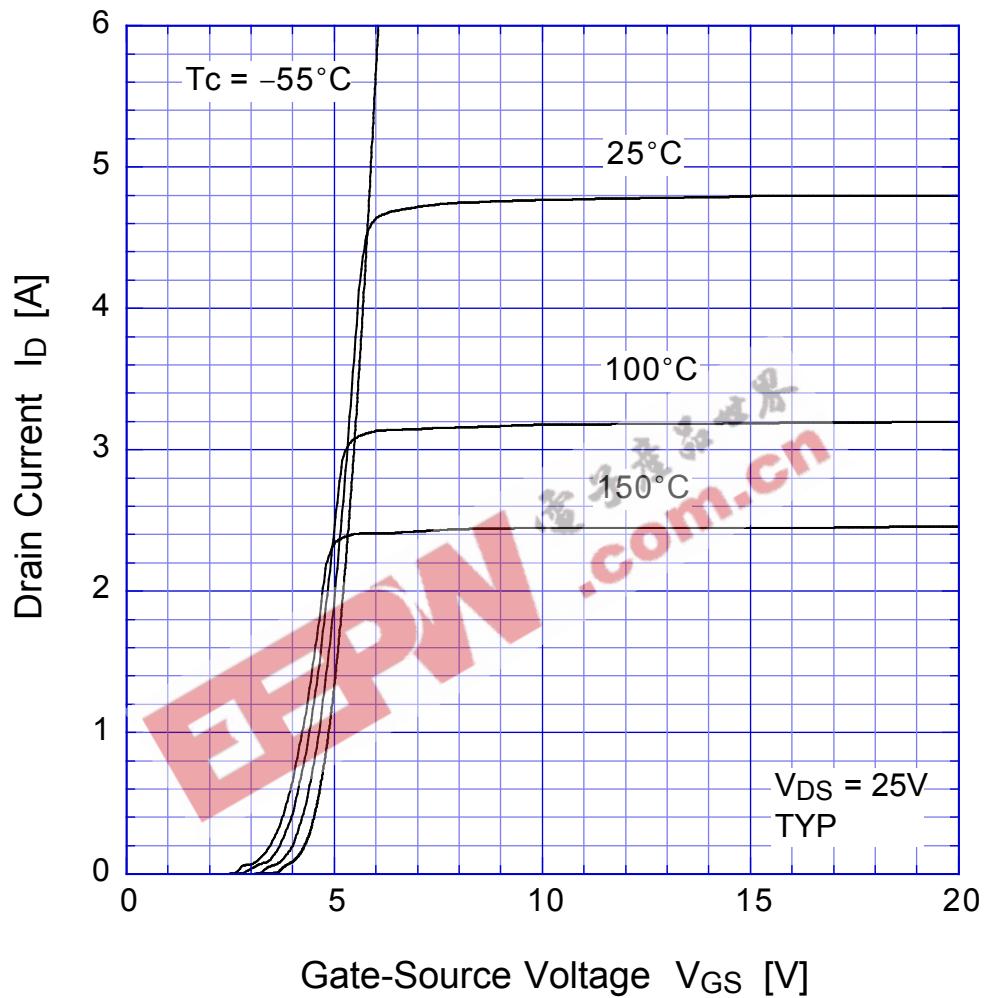
●Electrical Characteristics T<sub>c</sub> = 25°C

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	ID = 1mA, VGS = 0V	900			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	VDS = 900V, VGS = 0V			250	μA
Gate-Source Leakage Current	I <sub>GSS</sub>	VGS = ±30V, VDS = 0V			±0.1	
Forward Transconductance	g <sub>f</sub> s	ID = 1.5A, VDS = 10V	1.5	2.5		S
Static Drain-Source On-state Resistance	R <sub>D(S)ON</sub>	ID = 1.5A, VGS = 10V		3.5	4.7	Ω
Gate Threshold Voltage	V <sub>TH</sub>	ID = 1mA, VDS = 10V	2.5	3.0	3.5	V
Source-Drain Diode Forward Voltage	V <sub>SD</sub>	IS = 1.5A, VGS = 0V			1.5	
Thermal Resistance	θ <sub>jc</sub>	junction to case			2.5	°C/W
Total Gate Charge	Q <sub>g</sub>	VDD = 400V, VGS = 10V, ID = 3A		30		nC
Input Capacitance	C <sub>iss</sub>	VDS = 25V, VGS = 0V, f = 1MHZ		630		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			16		
Output Capacitance	C <sub>oss</sub>			67		
Turn-On Time	t <sub>on</sub>	ID = 1.5A, RL = 100Ω, VGS = 10V		40	70	ns
Turn-Off Time	t <sub>off</sub>			140	230	

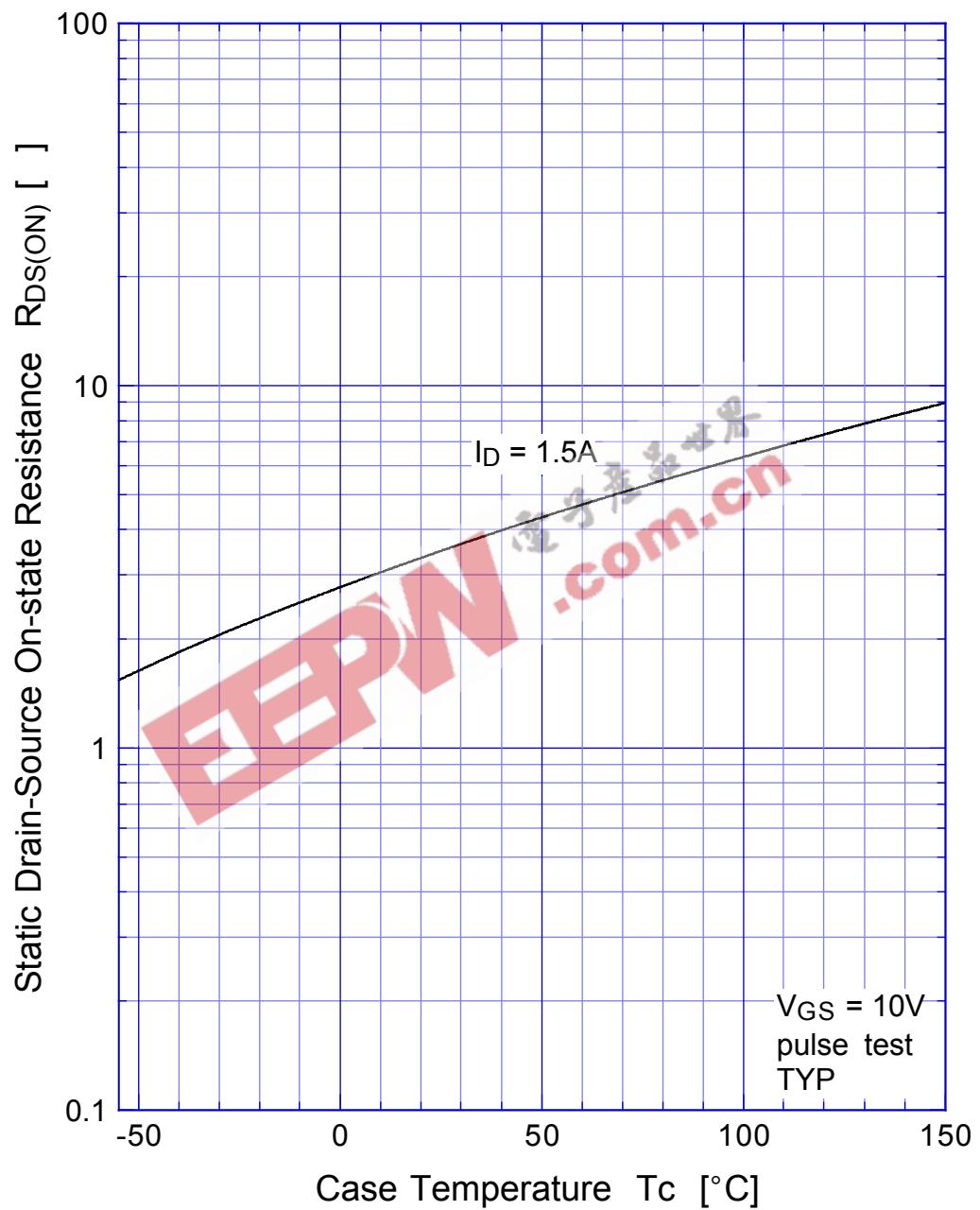
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## 2SK2664

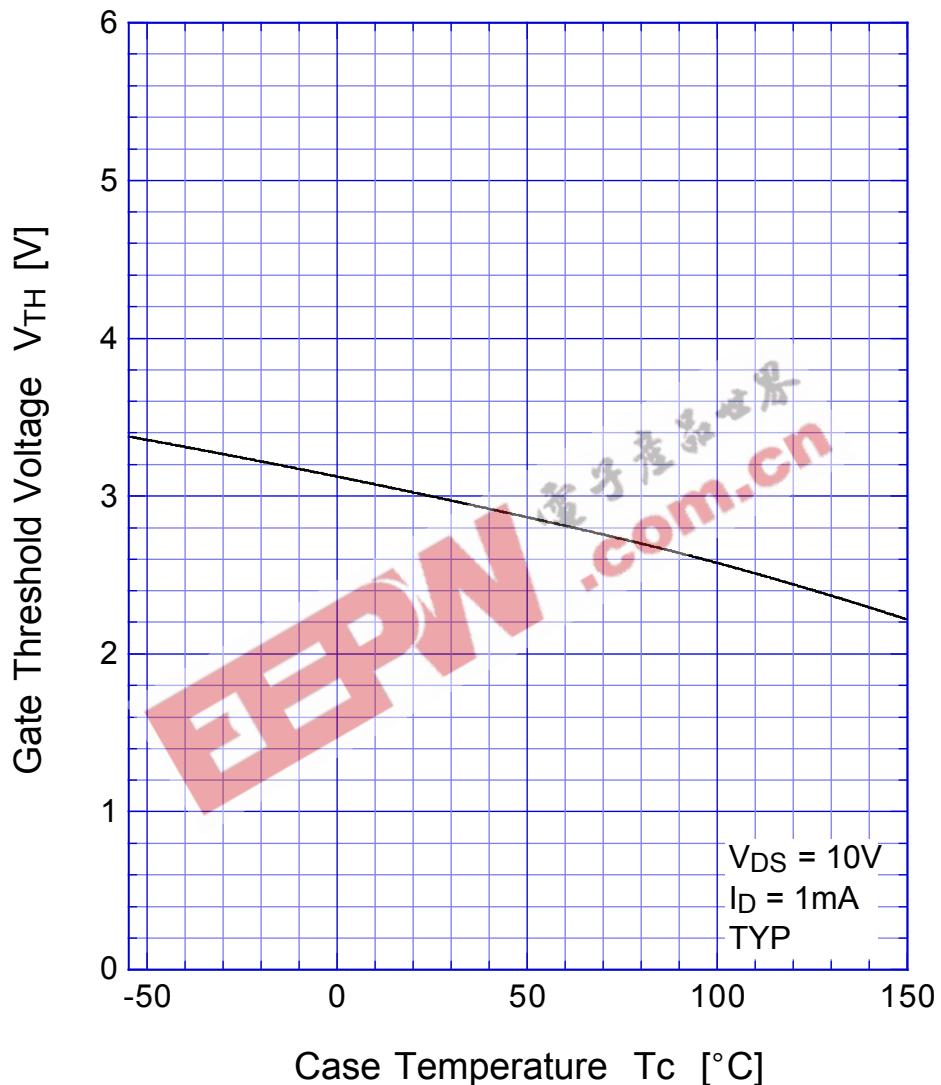
## Transfer Characteristics



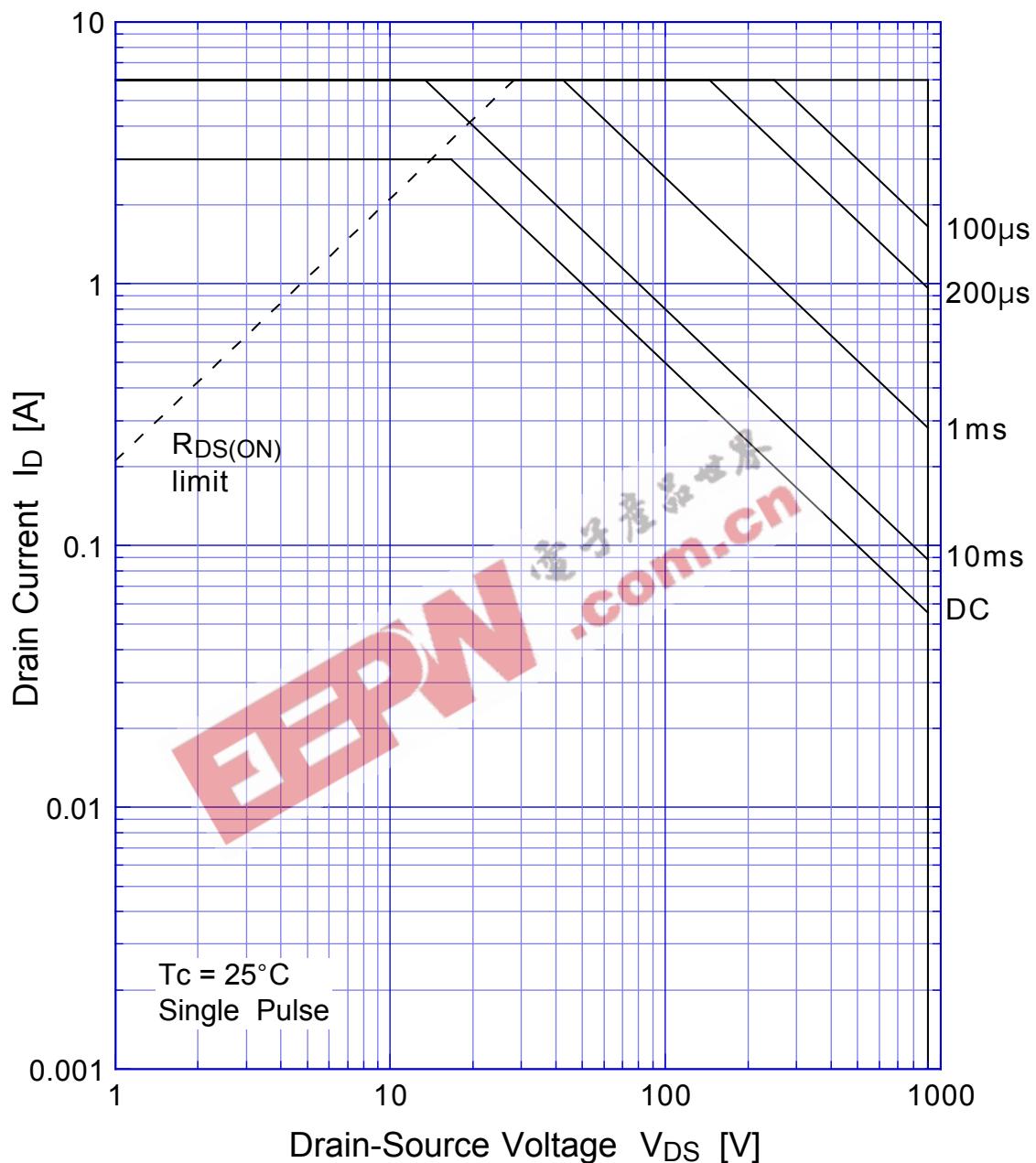
## 2SK2664 Static Drain-Source On-state Resistance



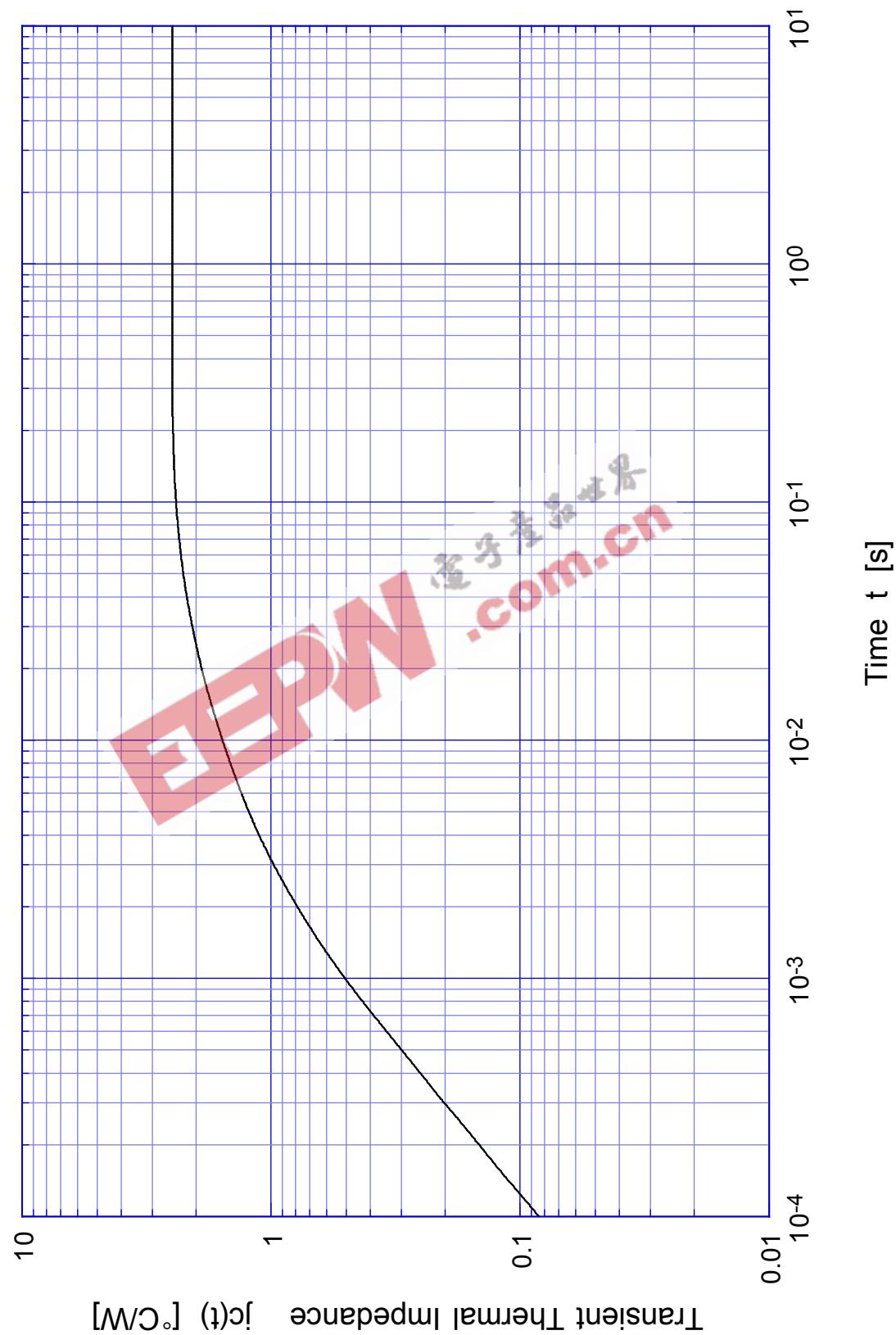
## 2SK2664 Gate Threshold Voltage



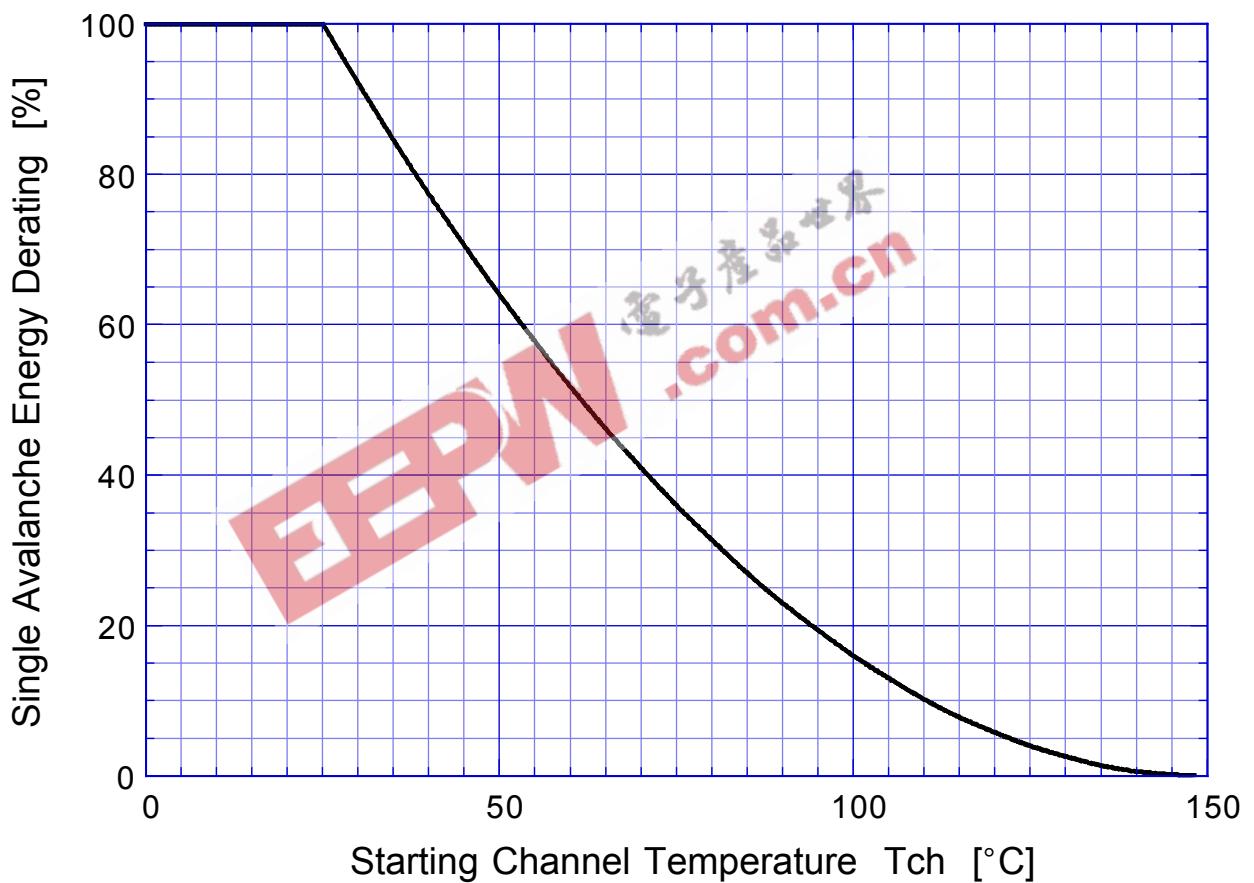
## 2SK2664 Safe Operating Area



## 2SK2664 Transient Thermal Impedance

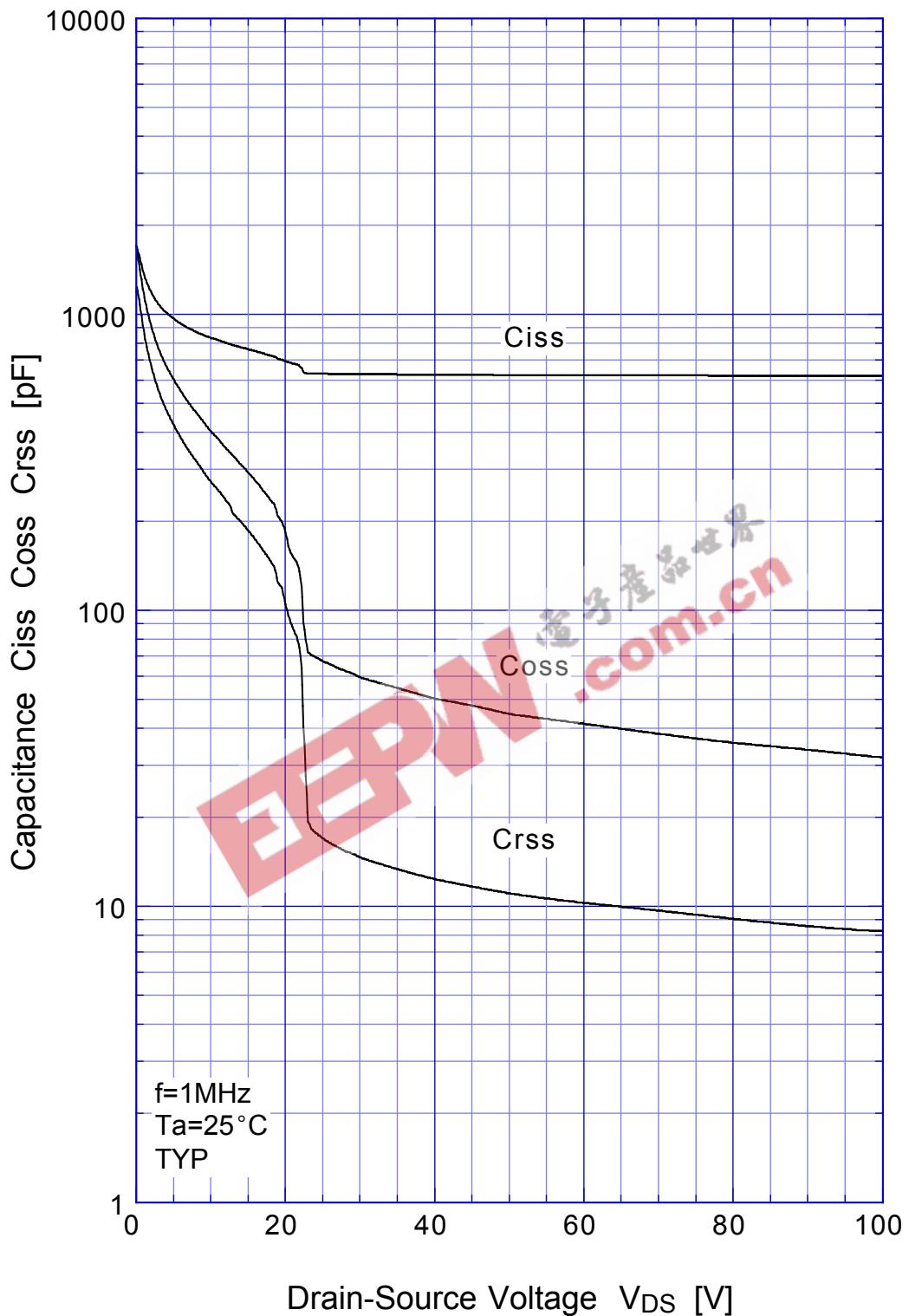


## 2SK2664 Single Avalanche Energy Derating



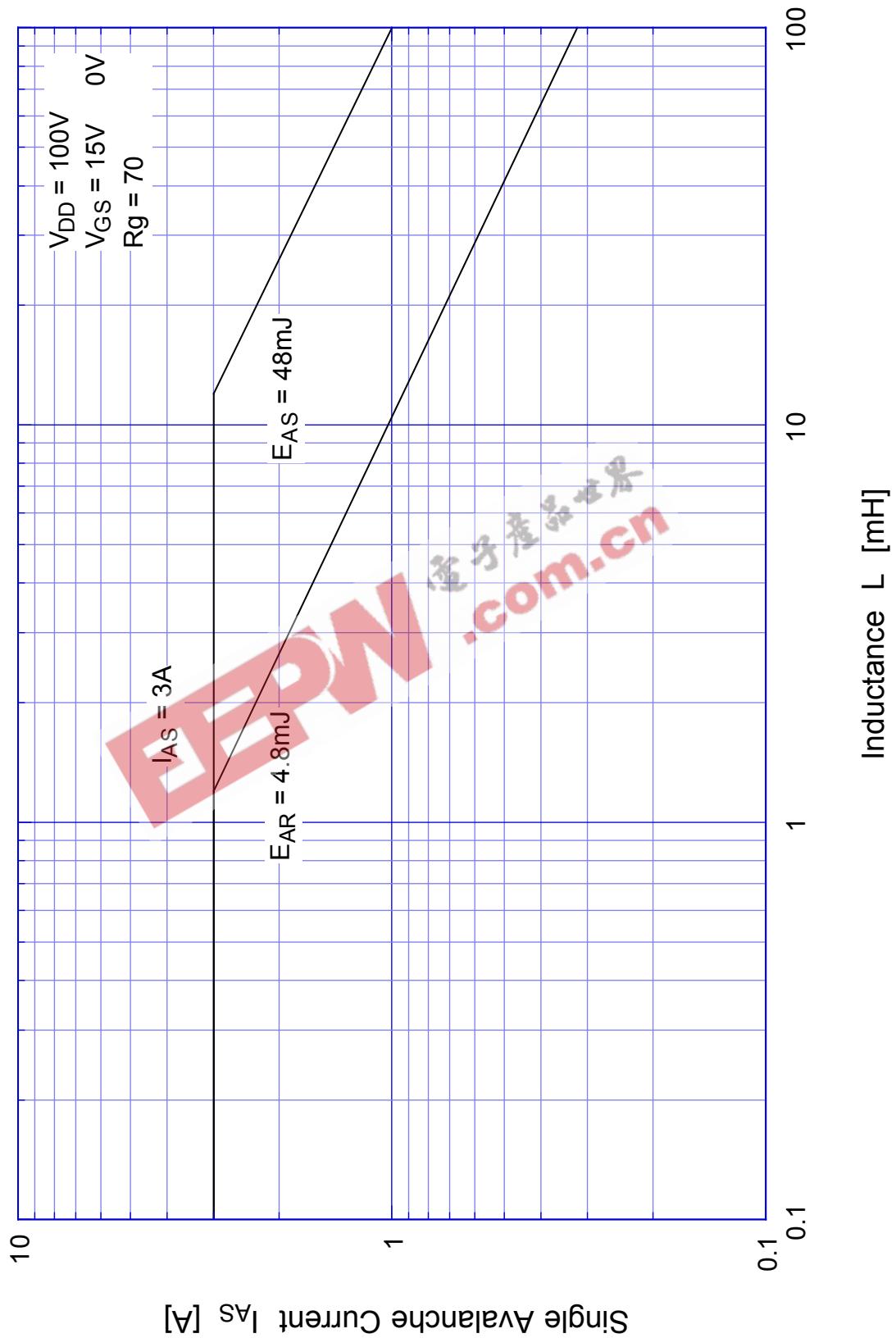
2SK2664

Capacitance



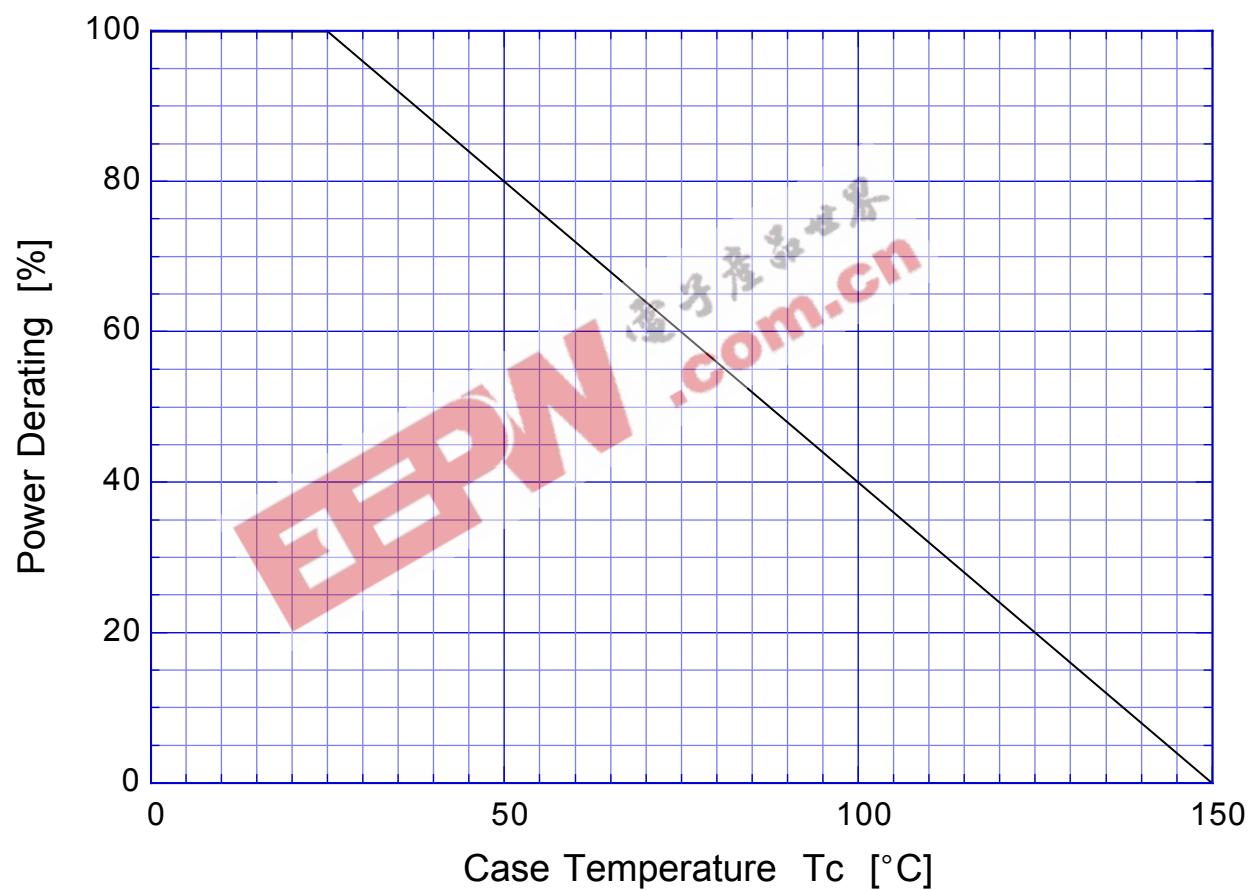
## 2SK2664 Single Avalanche Current - Inductive Load

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**2SK2664**

Power Derating



# 2SK2664

## Gate Charge Characteristics

